ON Semiconductor

Is Now



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Complementary ThermalTrak™ Transistors

The ThermalTrak family of devices has been designed to eliminate thermal equilibrium lag time and bias trimming in audio amplifier applications. They can also be used in other applications as transistor die protection devices.

Features

- Thermally Matched Bias Diode
- Instant Thermal Bias Tracking
- Absolute Thermal Integrity
- High Safe Operating Area
- Pb-Free Packages are Available*

Benefits

- Eliminates Thermal Equilibrium Lag Time and Bias Trimming
- Superior Sound Quality Through Improved Dynamic Temperature Response
- Significantly Improved Bias Stability
- Simplified Assembly
 - Reduced Labor Costs
 - Reduced Component Count
- High Reliability

Applications

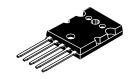
- High-End Consumer Audio Products
 - Home Amplifiers
 - Home Receivers
- Professional Audio Amplifiers
 - Theater and Stadium Sound Systems
 - Public Address Systems (PAs)



ON Semiconductor®

http://onsemi.com

BIPOLAR POWER TRANSISTORS 15 AMP, 260 VOLT, 200 WATT

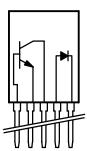


TO-264, 5 LEAD CASE 340AA STYLE 1

MARKING DIAGRAM

SCHEMATIC





NJLxxxxD = Device Code

xxxx = 3281 or 1302

G = Pb-Free Package A = Assembly Location

YY = Year WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping
NJL3281D	TO-264	25 Units / Rail
NJL3281DG	TO-264 (Pb-Free)	25 Units / Rail
NJL1302D	TO-264	25 Units / Rail
NJL1302DG	TO-264 (Pb-Free)	25 Units / Rail

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MAXIMUM RATINGS ($T_J = 25^{\circ}C$ unless otherwise noted)

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V _{CEO}	260	Vdc
Collector-Base Voltage	V _{CBO}	260	Vdc
Emitter-Base Voltage	V _{EBO}	5	Vdc
Collector–Emitter Voltage – 1.5 V	V _{CEX}	260	Vdc
Collector Current – Continuous – Peak (Note 1)	I _C	15 25	Adc
Base Current – Continuous	Ι _Β	1.5	Adc
Total Power Dissipation @ T _C = 25°C Derate Above 25°C	P _D	200 1.43	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	- 65 to +150	°C
DC Blocking Voltage	V _R	200	V
Average Rectified Forward Current	I _{F(AV)}	1.0	Α

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	0.625	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

ATTRIBUTES

Chara	cteristic	Value
ESD Protection	Human Body Model Machine Model	>8000 V > 400 V
Flammability Rating		UL 94 V-0 @ 0.125 in

^{1.} Pulse Test: Pulse Width = 5 ms, Duty Cycle < 10%.

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit		
OFF CHARACTERISTICS						
Collector–Emitter Sustaining Voltage $(I_C = 100 \text{ mAdc}, I_B = 0)$	V _{CEO(sus)}	260	_	Vdc		
Collector Cutoff Current (V _{CB} = 260 Vdc, I _E = 0)	I _{CBO}	-	50	μAdc		
Emitter Cutoff Current (V _{EB} = 5 Vdc, I _C = 0)	I _{EBO}	-	5	μAdc		
ON CHARACTERISTICS	<u>.</u>			•		
DC Current Gain	h _{FE}	75 75 75 75 75 45	150 150 150 150 150			
Collector–Emitter Saturation Voltage (I _C = 10 Adc, I _B = 1 Adc)	V _{CE(sat)}	-	3	Vdc		
DYNAMIC CHARACTERISTICS	<u>.</u>			•		
Current-Gain - Bandwidth Product (I _C = 1 Adc, V _{CE} = 5 Vdc, f _{test} = 1 MHz)	f⊤	30	_	MHz		
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f _{test} = 1 MHz)	C _{ob}	-	600	pF		
Maximum Instantaneous Forward Voltage (Note 2) ($i_F = 1.0 \text{ A}, T_J = 25^{\circ}\text{C}$) ($i_F = 1.0 \text{ A}, T_J = 150^{\circ}\text{C}$)	V _F	1.1 0.93		V		
Maximum Instantaneous Reverse Current (Note 2) (Rated dc Voltage, $T_J = 25^{\circ}C$) (Rated dc Voltage, $T_J = 150^{\circ}C$)	i _R	10 100		μΑ		
Maximum Reverse Recovery Time $(i_F = 1.0 \text{ A}, \text{ di/dt} = 50 \text{ A/}\mu\text{s})$	t _{rr}	10	00	ns		

^{2.} Diode Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

TYPICAL CHARACTERISTICS

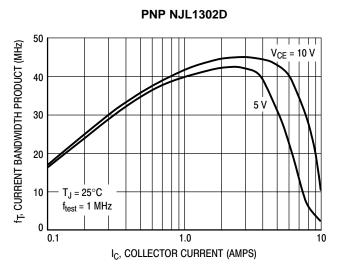


Figure 1. Typical Current Gain Bandwidth Product

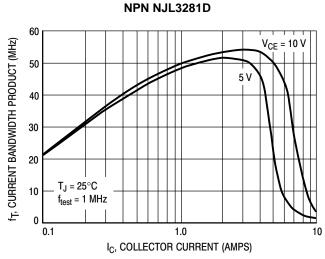


Figure 2. Typical Current Gain Bandwidth Product

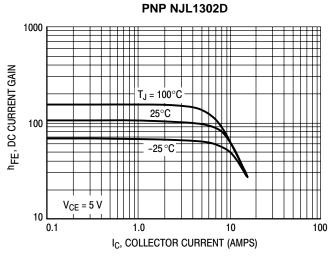


Figure 3. DC Current Gain, V_{CE} = 5 V

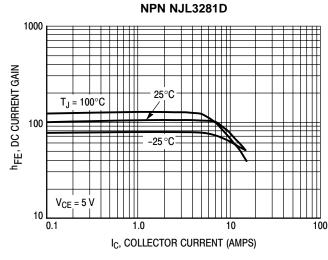


Figure 4. DC Current Gain, V_{CE} = 5 V

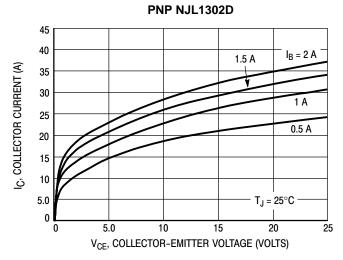


Figure 5. Typical Output Characteristics

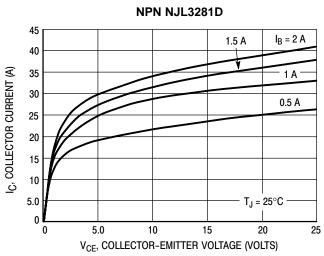


Figure 6. Typical Output Characteristics

TYPICAL CHARACTERISTICS

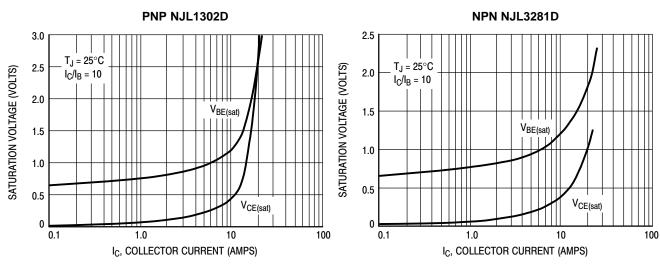


Figure 7. Typical Saturation Voltages

Figure 8. Typical Saturation Voltages

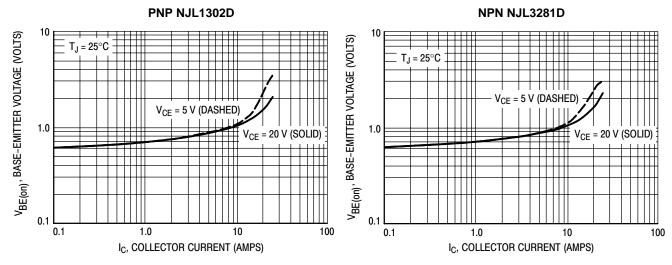


Figure 9. Typical Base-Emitter Voltage

Figure 10. Typical Base-Emitter Voltage

TYPICAL CHARACTERISTICS

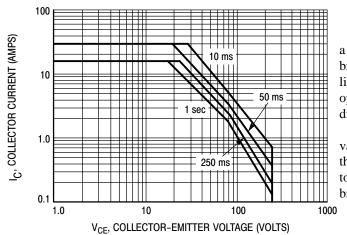


Figure 11. Active Region Safe Operating Area

There are two limitations on the power handling ability of a transistor; average junction temperature and secondary breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 11 is based on $T_{J(pk)} = 150$ °C; T_{C} is variable depending on conditions. At high case temperatures, thermal limitations will reduce the power than can be handled to values less than the limitations imposed by second breakdown.

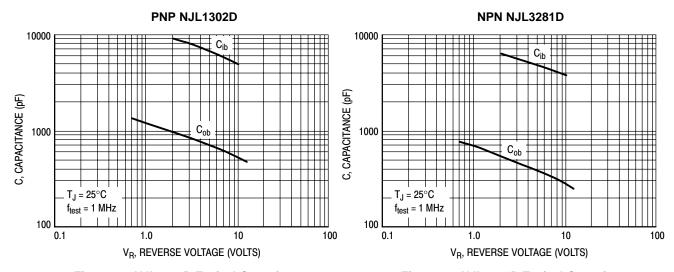


Figure 12. NJL1302D Typical Capacitance

Figure 13. NJL3281D Typical Capacitance

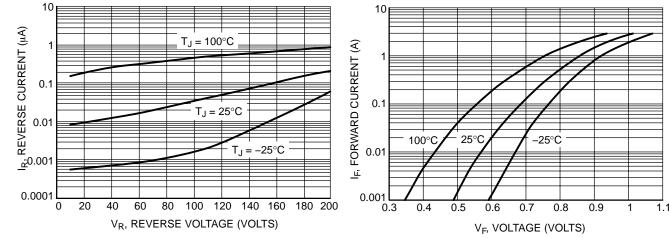


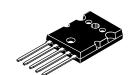
Figure 14. Typical Reverse Current

ThermalTrak is a trademark of Semiconductor Components Industries, LLC (SCILLC).

Figure 15. Typical Forward Voltage



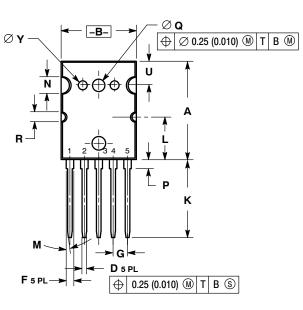


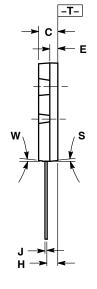


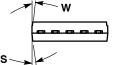
SCALE 1:2



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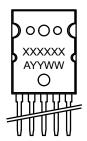


STYLE 1: PIN 1. BASE 2. EMITTER 3. COLLECTOR 4. ANODE 5. CATHODE

- NOTES:
 1. DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS				INCHES	;
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	25.857	25.984	26.111	1.018	1.023	1.028
В	19.761	19.888	20.015	0.778	0.783	0.788
С	4.699	4.890	5.182	0.185	0.199	0.204
D	1.	219 BS	С	0.0480 BSC		
Е	1.890	2.042	2.184	0.0748	0.0804	0.0860
F	1.	981 BS	С	0.0780 BSC		
G	3	.81 BSC	;	0	.150 BS	S
Н	2.667	2.718	2.769	0.1050	0.1070	0.1090
J	C	0.584 BSC		0.0230 BSC		SC
K	20.422	20.549	20.676	0.804	0.809	0.814
L	1	11.28 REF		0.444 REF		F
M	0 °		7 °	0 °		7 °
N		4.57 REF		0.180 REF		EF
Р	2.259	2.386	2.513	0.0889	0.0939	0.0989
Q	3.480 BSC		0.1370 BSC		SC	
R	2.54 REF		0.100 REF			
S	0 °		8 °	0 °		8 °
U	6.17 REF		0.243 REF		EF	
W	0 °		6°	0 °		6 °
Υ	2.388 BSC			0	.0940 B	SC

GENERIC MARKING DIAGRAM*



XXXXXX = Specific Device Code = Assembly Location Α

ΥY = Year WW = Work Week = Pb-Free Package G or ■

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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